

Notice of References Cited	Application/Control No. 10/762,625	Applicant(s)/Patent Under Reexamination BACHTOLD ET AL.	
	Examiner Douglas W. Owens	Art Unit 2811	Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	A	US-2004/0144972	07-2004	Dai et al.	257/020
	B	US-			
	C	US-			
	D	US-			
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	S.J. Wind. Carbon Nanotube Devices for Future Nanoelectronics. August, 2003. pages 236-239
	V	Nihey et al. A Top-Gate Carbon-Nanotube Field-Effect Transistor with a Titanium-Dioxide Insulator. July 15, 2002. The Japan Society of Applied Physics, Vol. 41 (2202) pp. L 1049 - L 1051
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	X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
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